



Complementary Dual General Purpose Transistor

Voltage

50V / -50V

Current

0.15 / -0.15A

Features

• Silicon PNP/NPN epitaxial type

Tr1: PNP Tr2: NPN

• Ideal for Low Power Amplification and Switching

AEC-Q101 qualified

• Lead free in compliance with EU RoHS 2.0

• Green molding compound as per IEC 61249 standard

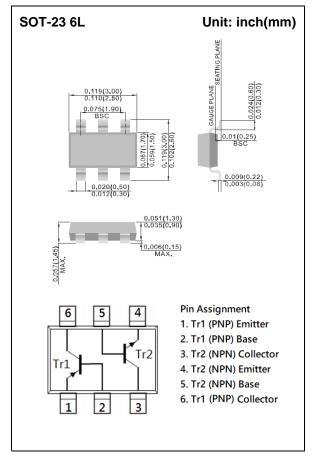
Mechanical Data

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.014 grams

Marking: 1AS



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	Tr1	Tr2	UNITS	
Collector-Base Voltage	V_{CBO}	50	-50		
Collector-Emitter Voltage	V_{CEO}	60	-60	V	
Emitter-Base Voltage	V _{EBO}	7	-6		
Collector Current (DC)	I _C	150	-150	mA	
Total Power Dissipation	P _D	300		mW	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55~150		°C	
Typical Thermal Resistance from Junction to Ambient (Note)	$R_{\theta JA}$	100		°C/W	

Note: Mounted on FR4 with 2oz. PCB at 1 inch square copper pad.





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Tr1 (PNP)							
OFF Characteristics							
Collector-Emitter Breakdown Voltage	BV _{CEO}	I_C = -1mA, I_B = 0A	-50	-	-		
Collector-Base Breakdown Voltage	BV _{CBO}	I _C = -50uA, I _E = 0A	-60	-	-	V	
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = -50uA, I _C = 0A	-6	-	-		
Collector-Base Cutoff Current	I _{CBO}	V _{CB} = -60V, I _E = 0A	-	-	-100	- n A	
Emitter-Base Cutoff Current	I _{EBO}	V _{EB} = -6V	-	-	-100	nA	
ON characteristics							
DC Current Gain	h _{FE}	V_{CE} = -6V I_{C} = -1mA	120	-	560	-	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I_C = -50mA, I_B = -5mA	-	-150	-500	mV	
Transition Frequency	f⊤	I_E = -2mA, V_{CE} = -12V f=100MHz	-	140	-	MHz	
Collector Output Capacitance	Сов	V_{CB} = -12V I_E = 0A, f =100MHz	-	4	5	pF	
Tr2 (NPN)							
OFF Characteristics	D) /	1 4 4	50				
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C = 1 \text{mA}, I_B = 0 \text{A}$	50	-	-		
Collector-Base Breakdown Voltage	BV _{CBO}	I _C = 50uA, I _E = 0A	60	-	-	V	
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = 50uA, I _C = 0A	7	-	-		
Collector-Base Cutoff Current	I _{CBO}	$V_{CB} = 60V$, $I_E = 0A$	-	-	100	nA	
Emitter-Base Cutoff Current	I _{EBO}	V _{EB} = 7V	-	-	100		
ON characteristics		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	100		500		
DC Current Gain	h _{FE}	V_{CE} = 6V I_{C} = 1mA	120	-	560	-	
Collector-Emitter Saturation Voltage Transition Frequency	V _{CE(SAT)}	I_C = 50mA, I_B = 5mA I_E = 2mA, V_{CE} = 12V f=100MHz	-	180	400	mV MHz	
Collector Output Capacitance Note: 1. Pulse width≤300us, Duty cycle≤29	С _{ОВ}	V _{CB} = 12V I _E = 0A, f=100MHz	-	2	3.5	pF	





TYPICAL CHARACTERISTIC CURVES

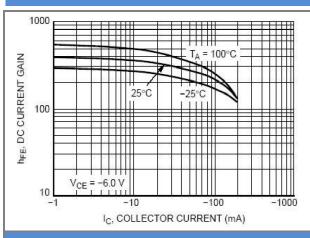


Fig.1 DC Current Gain

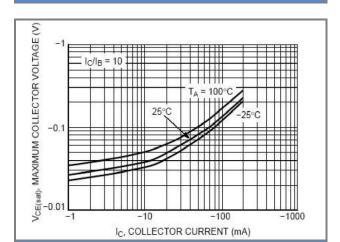
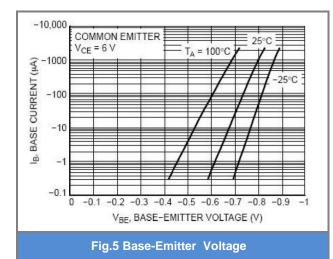


Fig.3 Collector-Emitter Saturation Voltage



Tr1 (PNP)

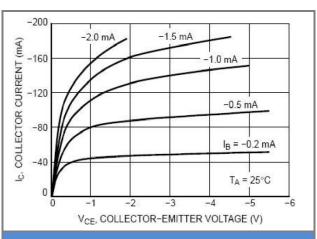


Fig.2 Collector Current

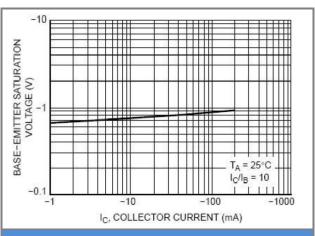


Fig.4 Base-Emitter Saturation Voltage





TYPICAL CHARACTERISTIC CURVES

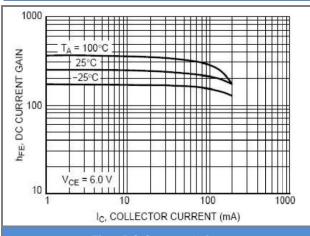


Fig.6 DC Current Gain

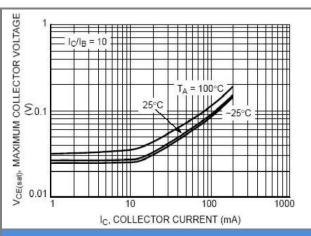
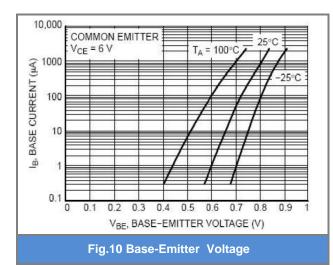


Fig.8 Collector-Emitter Saturation Voltage



<u>Tr2 (NPN)</u>

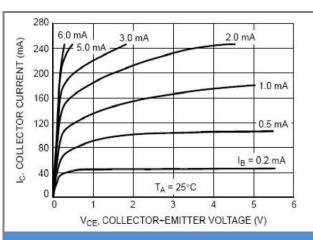


Fig.7 Collector Current

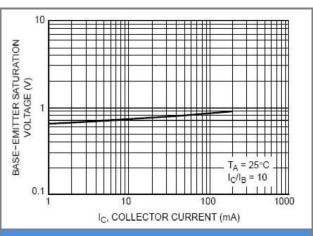


Fig.9 Base-Emitter Saturation Voltage

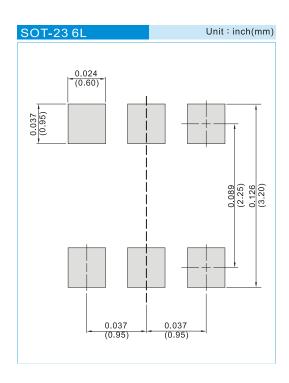




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
IMZ1AS-AU_S1_000A1	SOT-23 6L	3K pcs / 7" reel	1AS	Halogen free

Mounting Pad Layout







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